

SiC Schottky Barrier Diode

V_R	650V
I _F	15A
Q_C	23nC

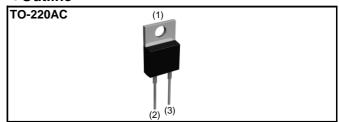
● Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

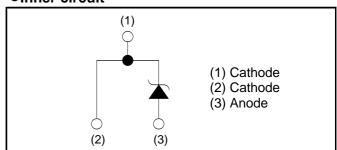
Construction

Silicon carbide epitaxial planer type

Outline



●Inner circuit



Packaging specifications

	Packaging	Tube	
	Reel size (mm)	-	
Typo	Tape width (mm)	-	
Туре	Basic ordering unit (pcs)	50	
	Taping code	С	
	Marking	SCS215AG	

● Absolute maximum ratings (Ti = 25°C)

Parameter	Symbol	Value	Unit	
Reverse voltage (repetitive peak)	V_{RM}	650	V	
Reverse voltage (DC)	V _R	650	V	
Continuous forward current	I _F	15* ¹	А	
		55* ²	А	
Surge no repetitive forward current	I _{FSM}	200* ³	А	
		43* ⁴	А	
Repetitive peak forward current	I _{FRM}	61* ⁵	А	
Total power disspation	P _D	110* ⁶	W	
Junction temperature	Tj	175	°C	
Range of storage temperature	Tstg	-55 to +175	°C	

^{*1} Tc=135°C *2 PW=8.3ms sinusoidal, Tj=25°C *3 PW=10μs square, Tj=25°C

^{*4} PW=8.3ms sinusoidal, Tj=150°C *5 Tc=100°C, Tj=150°C, Duty cycle=10% *6 Tc=25°C

●Electrical characteristics (Tj = 25°C)

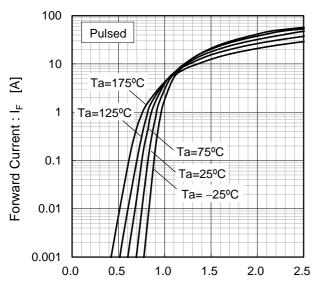
Parameter	Symbol	Conditions	Values			Linit
raiametei		Conditions	Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =0.3mA	600	-	-	V
Forward voltage	V _F	I _F =15A,Tj=25°C	-	1.35	1.55	V
		I _F =15A,Tj=150°C	-	1.55	-	V
		I _F =15A,Tj=175°C	-	1.63	-	V
Reverse current	I _R	V _R =600V,Tj=25°C	-	3	300	μΑ
		V _R =600V,Tj=150°C	-	45	1	μΑ
		V _R =600V,Tj=175°C	-	105	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	550	-	pF
		V _R =600V,f=1MHz	-	56	-	pF
Total capacitive charge	Qc	V _R =400V,di/dt=350A/μs	-	23	-	nC
Switching time	tc	V _R =400V,di/dt=350A/μs	1	18	-	ns

Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	$R_{\text{th(j-c)}}$	-	-	1.0	1.3	°C/W

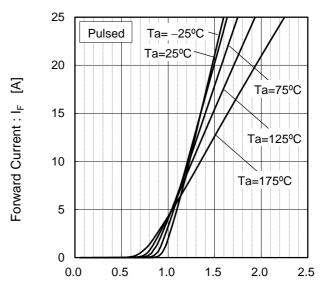
•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics



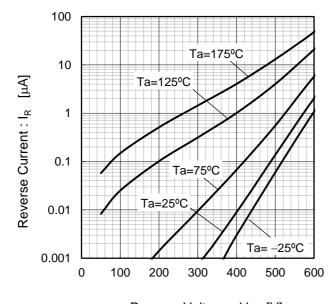
Forward Voltage : V_F [V]

Fig.2 V_F - I_F Characteristics



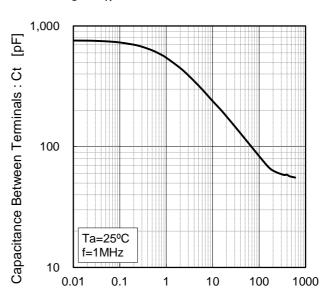
Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics



Reverse Voltage : V_R [V]

Fig.4 V_R-Ct Characteristics



Reverse Voltage : V_R [V]

•Electrical characteristic curves

Fig.5 Thermal Resistance vs. Pulse Width

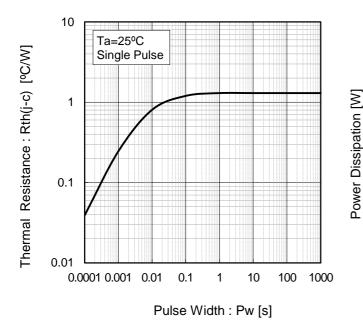
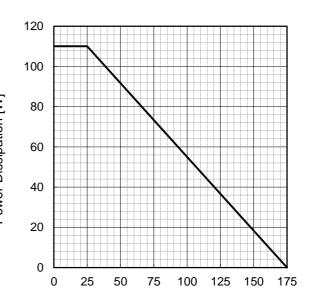


Fig.6 Power Dissipation



Case Temperature : Tc [°C]

Fig.7 Ip-Tc Derating Curve

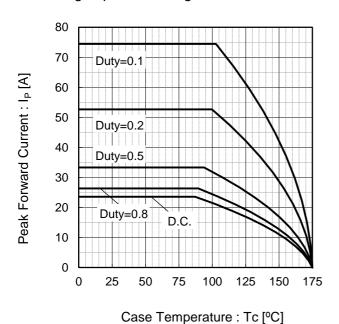
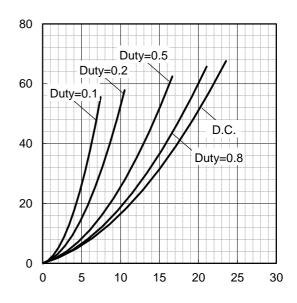


Fig.8 Io-Pf Characteristics

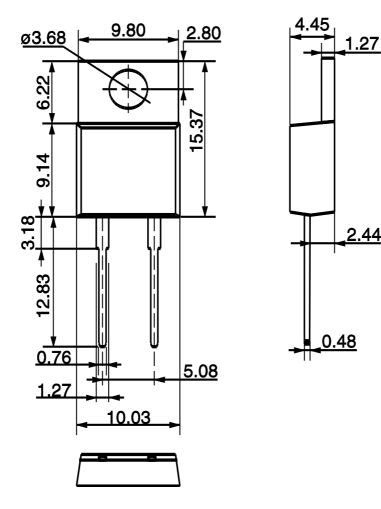


Average Rectified Forward Current : Io [A]

Power Dissipation [W]

●Dimensions (Unit:mm)

TO-220AC



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